

**Silicon NPN Darlington Power Transistor**

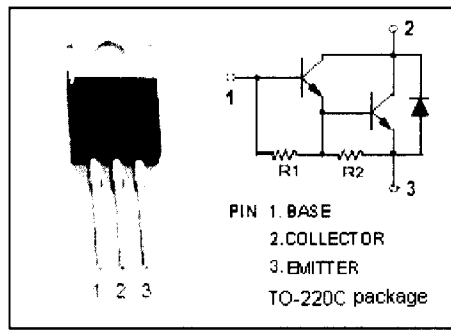
**BD901**

**DESCRIPTION**

- Collector-Emitter Breakdown Voltage-  
 :  $V_{(BR)CEO} = 100V(\text{Min})$
- High DC Current Gain  
 :  $h_{FE} = 750(\text{Min}) @ I_C = 3A$
- Collector Power Dissipation-  
 :  $P_C = 70W @ T_C = 25^\circ C$
- 8 A Continuous Collector Current
- Complement to Type BD902

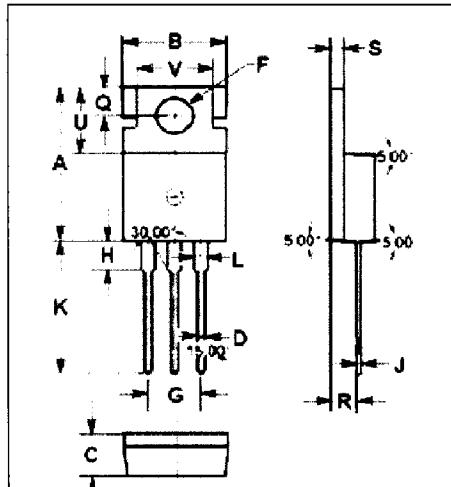
**APPLICATIONS**

- Designed for use as complementary AF push-pull output stage applications



**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ C$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	100	V
$V_{CEO}$	Collector-Emitter Voltage	100	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current-Continuous	8	A
$I_B$	Base Current-Continuous	0.3	A
$P_C$	Collector Power Dissipation @ $T_a=25^\circ C$	2	W
	Collector Power Dissipation @ $T_C=25^\circ C$	70	
$T_J$	Junction Temperature	150	$^\circ C$
$T_{stg}$	Storage Temperature Range	-65~150	$^\circ C$



DIM	mm	
	MIN	MAX
A	15.70	15.90
B	9.90	10.10
C	4.20	4.40
D	0.70	0.90
F	3.40	3.60
G	4.98	5.18
H	2.70	2.90
J	0.44	0.46
K	13.20	13.40
L	1.10	1.30
Q	2.70	2.90
R	2.50	2.70
S	1.29	1.31
U	6.45	6.65
V	8.66	8.86

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th-jc}$	Thermal Resistance, Junction to Case	1.79	$^\circ C/W$
$R_{th-ja}$	Thermal Resistance, Junction to Ambient	62.5	$^\circ C/W$



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## ELECTRICAL CHARACTERISTICS

$T_C=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C=100\text{mA}; I_B=0$	100			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=3\text{A}; I_B=12\text{mA}$			2.5	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C=3\text{A}; V_{CE}=3\text{V}$			2.5	V
$I_{CBO}$	Collector Cutoff Current	$V_{CB}=100\text{V}; I_E=0$			0.2	mA
		$V_{CB}=100\text{V}; I_E=0; T_C=100^\circ\text{C}$			2.0	
$I_{CEO}$	Collector Cutoff Current	$V_{CE}=50\text{V}; I_B=0$			0.5	mA
$I_{EBO}$	Emitter Cutoff Current	$V_{EB}=5\text{V}; I_C=0$			2	mA
$h_{FE}$	DC Current Gain	$I_C=3\text{A}; V_{CE}=3\text{V}$	750			

## Switching Times

$t_{on}$	Turn-On Time	$I_C=3\text{A}; I_{B1}=-I_{B2}=12\text{mA};$ $V_{BE(off)}=-3.5\text{V}; R_L=10\Omega;$ $t_p=20\mu\text{s}, \text{DutyCycle} \leq 2\%$		1		$\mu\text{s}$
$t_{off}$	Turn-Off Time			5		$\mu\text{s}$